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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	200MHz
Connectivity	CANbus, CSIO, EBI/EMI, I²C, LINbus, SD, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	120
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 24x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/s6e2c48h0agv2000a

Programmable Cyclic Redundancy Check (PRGCRC) Accelerator

The CRC accelerator helps a verify data transmission or storage integrity.

CCITT CRC16, IEEE-802.3 CRC32 and generating polynomial are supported.

- CCITT CRC16 generator polynomial: 0x1021
- IEEE-802.3 CRC32 generator polynomial: 0x04C11DB7
- Generating polynomial

SD Card Interface

It is possible to use the SD card that conforms to the following standards.

- Part 1 Physical Layer Specification version 3.01
- Part E1 SDIO Specification version 3.00
- Part A2 SD Host Controller Standard Specification version 3.00
- 1-bit or 4-bit data bus

I²S (Inter-IC Sound Bus) Interface (TX x 1 channel, RX x 1 channel)

- Supports three transfer protocols
  - I²S
  - Left justified
  - DSP mode
  - Separate clock generation block for flexible system integration options
- Master/slave mode selectable
- RX Only, TX Only or TX and RX simultaneous operation selectable
- Word length is programmable from 7-bits to 32 bits
- RX/TX FIFO integrated (RX: 66 words x 32-bits, TX: 66 words x 32-bits)
- DMA, interrupts, or polling based data transfer supported

High-Speed Quad SPI

Up to 66 MHz clock rates for very fast data transfers to and from SPI compatible devices.

Up to 256 Mbytes of memory mapped address space.

- Single data rate (SDR)
- Supports single, dual, and quad data modes
- Built-in direct mode and command sequencer mode
  - Direct mode: Access by use of transmission FIFO/reception FIFO (up to16 word x 32 bit)
  - Command sequencer mode: Automatic access assigned to external device area.

Clock and Reset

- Clocks

Five clock sources (two external oscillators, two internal CR oscillators, and Main PLL) that are dynamically selectable.

  - Main clock: 4 MHz to 48 MHz
  - Sub clock: 32.768 kHz
  - High-speed internal CR clock: 4 MHz
  - Low-speed internal CR clock: 100 kHz
  - Main PLL Clock

- Resets
  - Reset requests from INITX pin
  - Power on reset
  - Software reset
  - Watchdog timer reset
  - Low-voltage detector reset
  - Clock supervisor reset

Clock Supervisor (CSV)

Clocks generated by internal CR oscillators are used to supervise abnormality of the external clocks.

- External OSC clock failure (clock stop) is detected, reset is asserted.
- External OSC frequency anomaly is detected, interrupt or reset is asserted.

Low-Voltage Detector (LVD)

This Series include two-stage monitoring of voltage on the VCC pins. When the voltage falls below the voltage that has been set, the low-voltage detector function generates an interrupt or reset.

- LVD1: error reporting via interrupt
- LVD2: auto-reset operation

Low-power Consumption Mode

Six low power consumption modes are supported.

- Sleep
- Timer
- RTC
- Stop
- Deep standby RTC (selectable from with/without RAM retention)
- Deep standby stop (selectable from with/without RAM retention)

Peripheral Clock Gating

The system can reduce the current consumption of the total system with gating the operation clocks of peripheral functions not used.

4. Pin Descriptions

List of Pin Functions

The number after the underscore ("_") in pin names such as XXX_1 and XXX_2 indicates the relocated port number. For these pins, there are multiple pins that provide the same function for the same channel.

Use the extended port function register (EPFR) to select the pin.

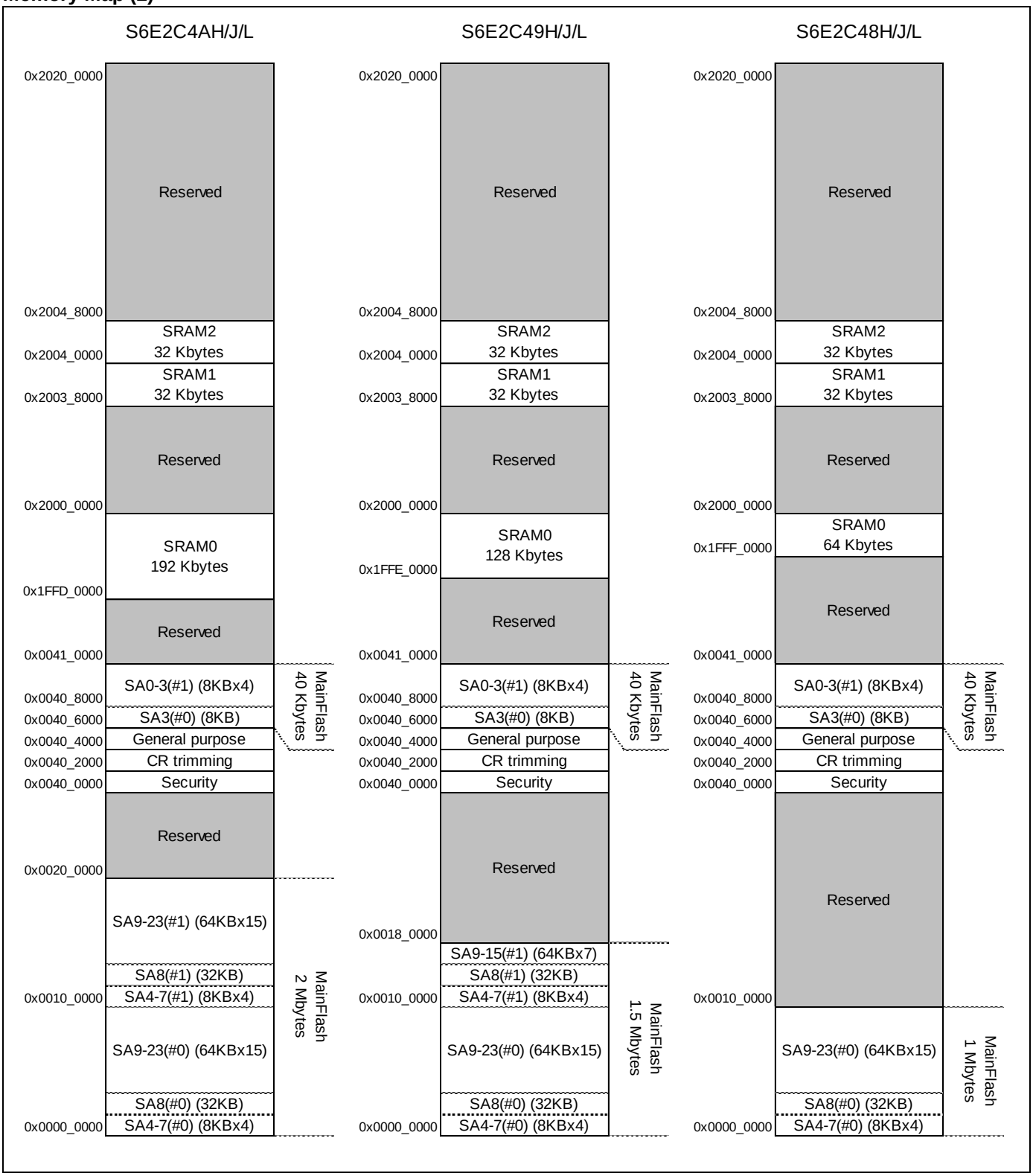
Pin No				Pin Name	I/O circuit type	Pin state type
LQQ216	LQP176	LQS144	LBE192			
1	1	1	C1	VCC	-	-
2	2	2	B2	PA0 RTO20_0 (PPG20_0) TIOA8_0 AIN2_0 INT00_0 MADATA00_0	G	K
3	3	3	C2	PA1 RTO21_0 (PPG20_0) TIOA9_0 BIN2_0 MADATA01_0	G	I
4	4	4	C3	PA2 RTO22_0 (PPG22_0) TIOA10_0 ZIN2_0 MADATA02_0	G	I
5	5	5	D5	PA3 RTO23_0 (PPG22_0) TIOA11_0 MADATA03_0	G	I
6	6	6	D2	PA4 RTO24_0 (PPG24_0) TIOA12_0 MADATA04_0	G	I
7	7	7	D1	PA5 SIN1_0 RTO25_0 (PPG24_0) TIOA13_0 INT01_0 MADATA05_0	G	K

Pin No				Pin Name	I/O circuit type	Pin state type
LQQ216	LQP176	LQS144	LBE192			
33	-	-	-	P5C TIOA11_2 MADATA28_0 RTCCO_1 SUBOUT_1	E	I
34	24	-	G6	P30 RX0_1 TIOA13_2 INT03_2 MDQM2_0 I2SDI0_0	E	K
35	25	-	H4	P31 TX0_1 TIOB13_2 MDQM3_0 I2SCK0_0	E	I
36	26	21	H2	P32 BIN2_1 INT19_0 S_DATA1_0	L	K
37	27	22	J1	P33 FRCK0_0 ZIN2_1 S_DATA0_0	L	I
38	28	23	H3	P34 IC03_0 INT00_1 S_CLK_0	L	K
39	29	24	H1	VCC	-	-
40	30	25	H5	VSS	-	-
41	31	26	H6	P35 IC02_0 INT01_1 S_CMD_0	L	K
42	32	27	J5	P36 IC01_0 INT02_1 S_DATA3_0	L	K
43	33	28	J4	P37 IC00_0 INT03_1 S_DATA2_0	L	K

Module	Pin name	Function	Pin No			
			LQQ 216	LQP 176	LQS 144	LBE 192
Base Timer 0	TIOA0_0	Base Timer ch.0 TIOA Pin	56	46	38	N2
	TIOA0_1		45	35	30	J2
	TIOA0_2		114	94	78	L11
	TIOB0_0	Base Timer ch.0 TIOB Pin	82	67	57	L8
	TIOB0_1		21	-	-	-
	TIOB0_2		115	95	79	K13
Base Timer 1	TIOA1_0	Base Timer ch.1 TIOA Pin	57	47	39	N3
	TIOA1_1		46	36	31	K1
	TIOA1_2		116	96	80	K12
	TIOB1_0	Base Timer ch.1 TIOB Pin	83	68	58	K8
	TIOB1_1		22	-	-	-
	TIOB1_2		123	99	83	J13
Base Timer 2	TIOA2_0	Base Timer ch.2 TIOA Pin	58	48	40	M3
	TIOA2_1		47	37	32	K2
	TIOA2_2		124	100	84	J12
	TIOB2_0	Base Timer ch.2 TIOB Pin	84	69	59	J8
	TIOB2_1		26	-	-	-
	TIOB2_2		125	101	85	J11
Base Timer 3	TIOA3_0	Base Timer ch.3 TIOA Pin	59	49	41	L4
	TIOA3_1		48	38	33	K3
	TIOA3_2		130	106	86	H9
	TIOB3_0	Base Timer ch.3 TIOB Pin	91	76	60	K9
	TIOB3_1		27	-	-	-
	TIOB3_2		131	107	87	H12
Base Timer 4	TIOA4_0	Base Timer ch.4 TIOA Pin	60	50	42	M4
	TIOA4_1		49	39	34	K4
	TIOA4_2		132	108	88	H14
	TIOB4_0	Base Timer ch.4 TIOB Pin	92	77	61	P10
	TIOB4_1		28	-	-	-
	TIOB4_2		133	109	89	G14
Base Timer 5	TIOA5_0	Base Timer ch.5 TIOA Pin	61	51	43	N4
	TIOA5_1		50	40	35	L1
	TIOA5_2		134	110	90	H13
	TIOB5_0	Base Timer ch.5 TIOB Pin	93	78	62	N10
	TIOB5_1		29	-	-	-
	TIOB5_2		135	111	91	H11
Base Timer 6	TIOA6_0	Base Timer ch.6 TIOA Pin	179	147	117	D9
	TIOA6_1		85	70	-	N8
	TIOA6_2		200	-	-	-
	TIOB6_0	Base Timer ch.6 TIOB Pin	178	146	116	B8
	TIOB6_1		86	71	-	M8
	TIOB6_2		199	-	-	-

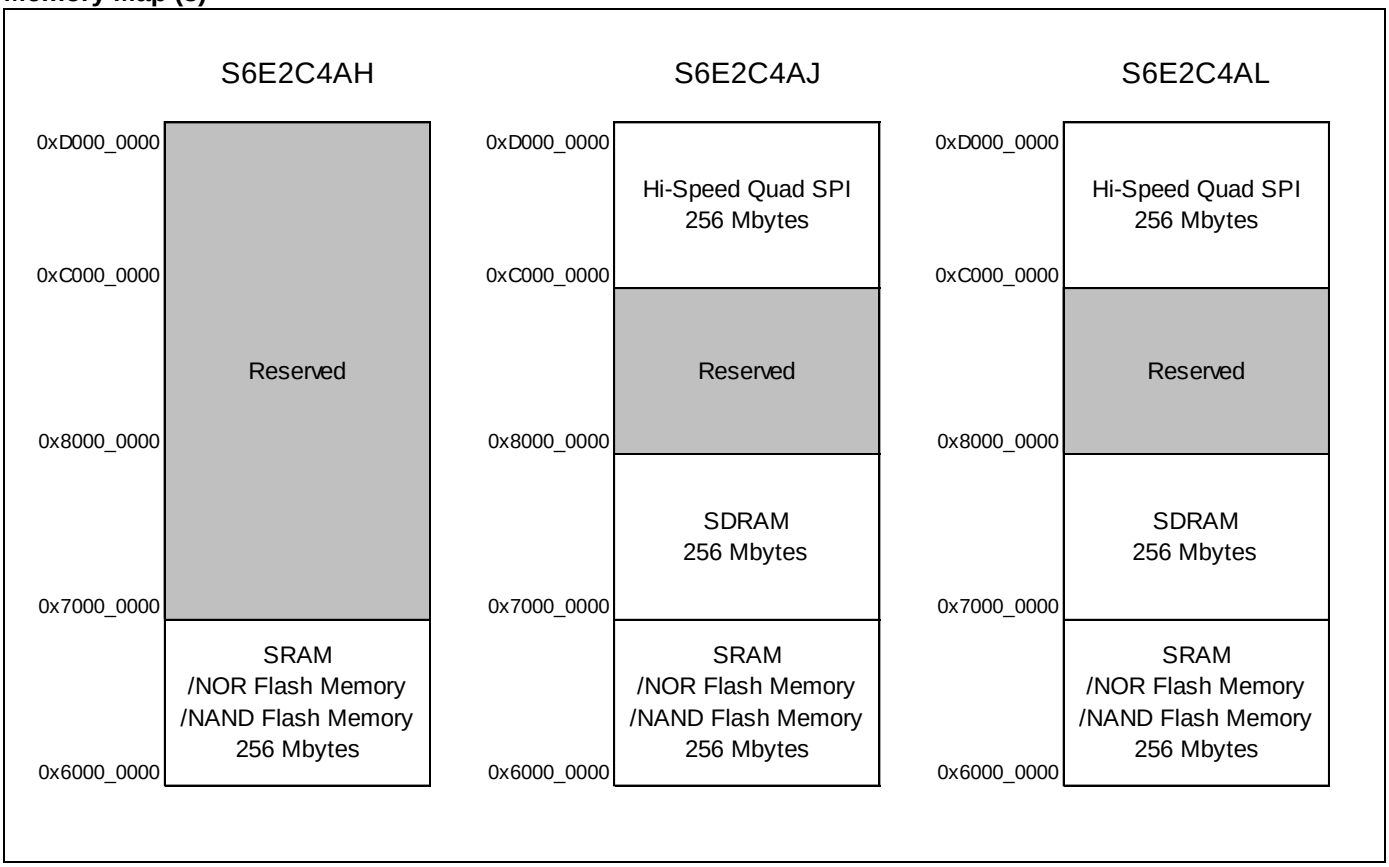
Module	Pin name	Function	Pin No			
			LQQ 216	LQP 176	LQS 144	LBE 192
Debugger	SWCLK	Serial wire debug interface clock input pin	165	135	111	A12
	SWDIO	Serial wire debug interface data input / output pin	167	137	113	B12
	SWO	Serial wire viewer output pin	168	138	114	B11
	TCK	JTAG test clock input pin	165	135	111	A12
	TDI	JTAG test data input pin	166	136	112	C12
	TDO	JTAG debug data output pin	168	138	114	B11
	TMS	JTAG test mode state input/output pin	167	137	113	B12
	TRACECLK	Trace CLK output pin of ETM/HTM	131	107	87	H12
	TRACED0	Trace data output pin of ETM/ Trace data output pin of HTM	132	108	88	H14
	TRACED1		133	109	89	G14
	TRACED2		134	110	90	H13
	TRACED3		135	111	91	H11
	TRACED4	Trace data output pin of HTM	138	112	-	G13
	TRACED5		139	113	-	F14
	TRACED6		140	114	-	G12
	TRACED7		141	115	-	G11
	TRACED8		119	-	-	-
	TRACED9		120	-	-	-
	TRACED10		121	-	-	-
	TRACED11		122	-	-	-
	TRACED12		148	-	-	-
	TRACED13		149	-	-	-
	TRACED14		150	-	-	-
	TRACED15		151	-	-	-
	TRSTX	JTAG test reset Input pin	164	134	110	B13

Memory Map (2)



* See S6E2CC/S6E2C5/S6E2C4/S6E2C3/S6E2C2/S6E2C1 Series Flash Programming Manual to confirm the detail of flash Memory.

Memory Map (3)


S6E2C4AH
0xD000_0000
0xC000_0000
0x8000_0000
0x7000_0000
0x6000_0000
Reserved
SRAM
/NOR Flash Memory
/NAND Flash Memory
256 Mbytes
S6E2C4AJ
0xD000_0000
0xC000_0000
0x8000_0000
0x7000_0000
0x6000_0000
Hi-Speed Quad SPI
256 Mbytes
Reserved
SDRAM
256 Mbytes
SRAM
/NOR Flash Memory
/NAND Flash Memory
256 Mbytes
S6E2C4AL
0xD000_0000
0xC000_0000
0x8000_0000
0x7000_0000
0x6000_0000
Hi-Speed Quad SPI
256 Mbytes
Reserved
SDRAM
256 Mbytes
SRAM
/NOR Flash Memory
/NAND Flash Memory
256 Mbytes

Pin Status Type	Function Group	Power-On Reset or Low-Voltage Detection State	INITX Input State	Device Internal Reset State	Run mode or Sleep mode State	Timer mode, RTC mode, or Stop mode State		Deep Standby RTC mode or Deep Standby Stop mode State		Return From Deep Standby Mode State
		Power Supply Unstable	Power Supply Stable		Power Supply Stable	Power Supply Stable		Power Supply Stable		Power Supply Stable
		-	INITX=0	INITX=1	INITX=1	INITX=1		INITX=1		INITX=1
		-	-	-	-	SPL=0	SPL=1	SPL=0	SPL=1	-
J	Analog output selected	Hi-Z	Hi-Z/ input enabled	Hi-Z/ input enabled	Maintain previous state	*2	*3	GPIO selected, internal input fixed at 0	Hi-Z/internal input fixed at 0	GPIO selected
	External interrupt enable selected					Maintain previous state	Maintain previous state			
	Resource other than above selected						Hi-Z/internal input fixed at 0			
	GPIO selected									
K	External interrupt enable selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Maintain previous state	GPIO selected, internal input fixed at 0	Hi-Z/internal input fixed at 0	GPIO selected
	Resource other than above selected	Hi-Z	Hi-Z/ input enabled	Hi-Z/ input enabled			Hi-Z/internal input fixed at 0			
	GPIO selected									
L	Analog input selected	Hi-Z	Hi-Z/ internal input fixed at 0/ analog input enabled	Hi-Z/ internal input fixed at 0/ analog input enabled	Hi-Z/ internal input fixed at 0/ analog input enabled	Hi-Z/ internal input fixed at 0/ analog input enabled	Hi-Z/ internal input fixed at 0/ analog input enabled	Hi-Z/ internal input fixed at 0/ analog input enabled	Hi-Z/ internal input fixed at 0/ analog input enabled	Hi-Z/ internal input fixed at 0/ analog input enabled
	Resource other than above selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Hi-Z/internal input fixed at 0	GPIO selected, internal input fixed at 0	Hi-Z/internal input fixed at 0	GPIO selected
	GPIO selected									

Package thermal resistance and maximum permissible power for each package are shown below.
The operation is guaranteed maximum permissible power or less for semiconductor devices.

Table for Package Thermal Resistance and Maximum Permissible Power

Package	Printed Circuit Board	Thermal Resistance θ_{JA} (°C/W)	Maximum Permissible Power (mW)	
			T_A = +85°C	T_A = +105°C
LQS144 (0.5-mm pitch)	Single-layered both sides	48	833	417
	4 layers	33	1212	606
LQP176 (0.5-mm pitch)	Single-layered both sides	45	889	444
	4 layers	31	1290	645
LQQ216 (0.4-mm pitch)	Single-layered both sides	46	870	435
	4 layers	32	1250	625
LBE192 (0.8-mm pitch)	Single-layered both sides	-	-	-
	4 layers	35	1143	571

WARNING:

1. *The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.*
2. *Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.*
3. *No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet.*
4. *Users considering application outside the listed conditions are advised to contact their representatives beforehand.*

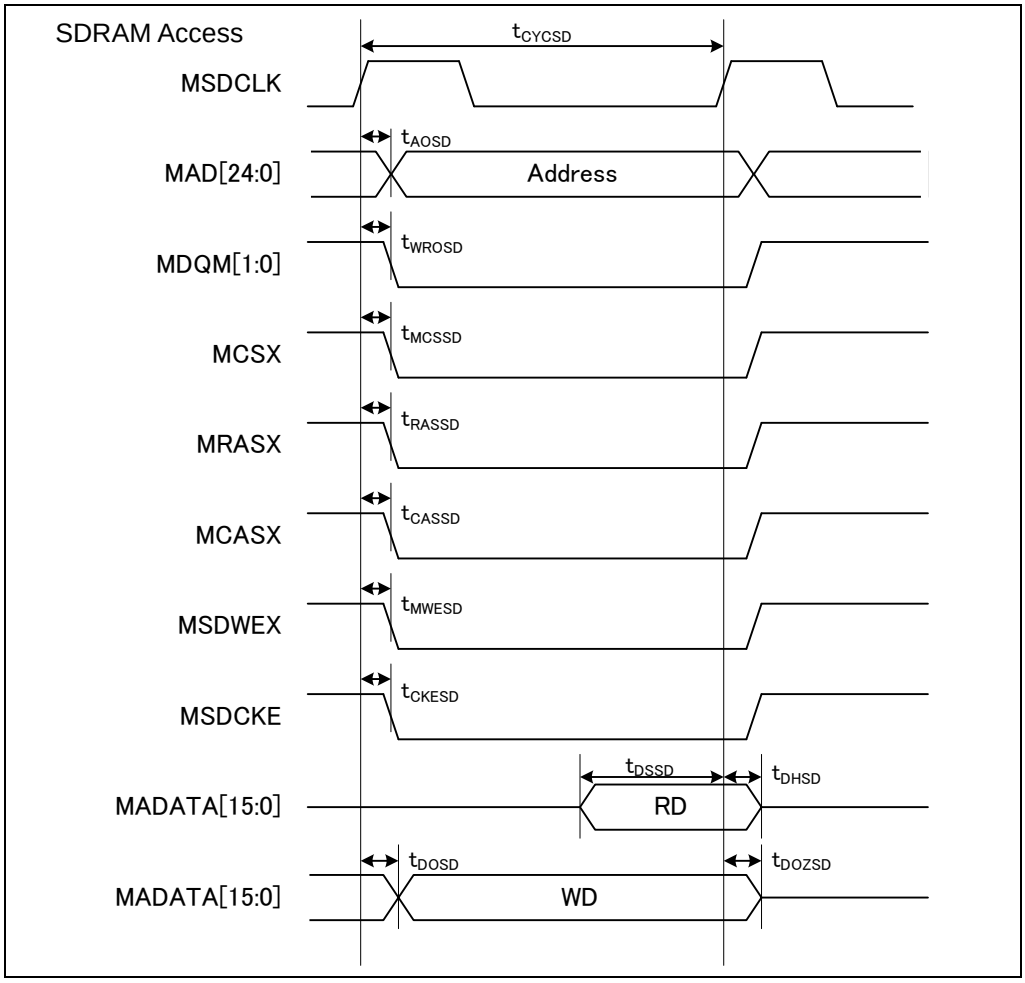
Separate Bus Access Asynchronous SRAM Mode

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
MOEX Minimum pulse width	t_{OEW}	MOEX	-	MCLK×n-3	-	ns	
MCSX ↓ →Address output delay time	t_{CSL-AV}	MCSX[7: 0], MAD[24: 0]	-	-9	+9	ns	
MOEX ↑ →Address hold time	t_{OEH-AX}	MOEX, MAD[24: 0]	-	0	MCLK×m+9	ns	
MCSX ↓ → MOEX ↓ delay time	$t_{CSL-OEL}$	MOEX, MCSX[7: 0]	-	MCLK×m-9	MCLK×m+9	ns	
MOEX ↑ → MCSX ↑ time	$t_{OEH-CSH}$		-	0	MCLK×m+9	ns	
MCSX ↓ → MDQM ↓ delay time	$t_{CSL-RDQML}$	MCSX, MDQM[3: 0]	-	MCLK×m-9	MCLK×m+9	ns	
Data set up→MOEX ↑ time	t_{DS-OE}	MOEX, MADATA[31: 0]	-	20	-	ns	
MOEX ↑ → Data hold time	t_{DH-OE}	MOEX, MADATA[31: 0]	-	0	-	ns	
MWEX Minimum pulse width	t_{WEW}	MWEX	-	MCLK×n-3	-	ns	
MWEX ↑ →Address output delay time	t_{WEH-AX}	MWEX, MAD[24: 0]	-	0	MCLK×m+9	ns	
MCSX ↓ → MWEX ↓ delay time	$t_{CSL-WEL}$	MWEX, MCSX[7: 0]	-	MCLK×n-9	MCLK×n+9	ns	
MWEX ↑ → MCSX ↑ delay time	$t_{WEH-CSH}$		-	0	MCLK×m+9	ns	
MCSX ↓ → MDQM ↓ delay time	$t_{CSL-WDQML}$	MCSX, MDQM[3: 0]	-	MCLK×n-9	MCLK×n+9	ns	
MCSX ↓ → Data output time	t_{CSL-DX}	MCSX, MADATA[31: 0]	-	MCLK-9	MCLK+9	ns	
MWEX ↑ → Data hold time	t_{WEH-DX}	MWEX, MADATA[31: 0]	-	0	MCLK×m+9	ns	

Note:

- *When the external load capacitance C_L = 30 pF (m = 0 to 15, n = 1 to 16)*

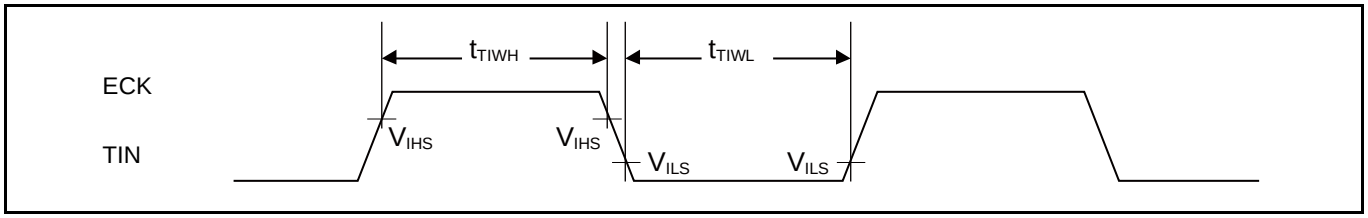

SDRAM Access
tCYCSD
MSDCLK
tAOSD
MAD[24:0]
Address
tWROSD
MDQM[1:0]
tMCSSD
MCSX
tRASSD
MRASX
tCASSD
MCASX
tMWESD
MSDWEX
tCKESD
MSDCKE
tDSSD
tDHSD
MADATA[15:0]
RD
tDOSD
tDOZSD
MADATA[15:0]
WD

12.4.11 Base Timer Input Timing

Timer Input Timing

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

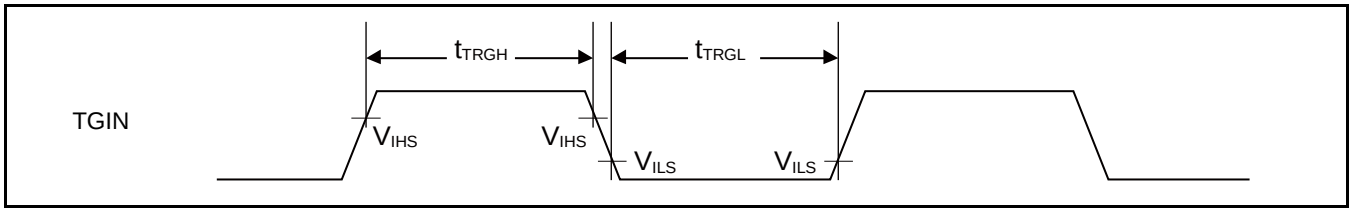
Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
Input pulse width	t_{TIWH}, t_{TIWL}	TIOAn/TIOBn (when using as ECK, TIN)	-	$2t_{CYCP}$	-	ns	



Trigger Input Timing

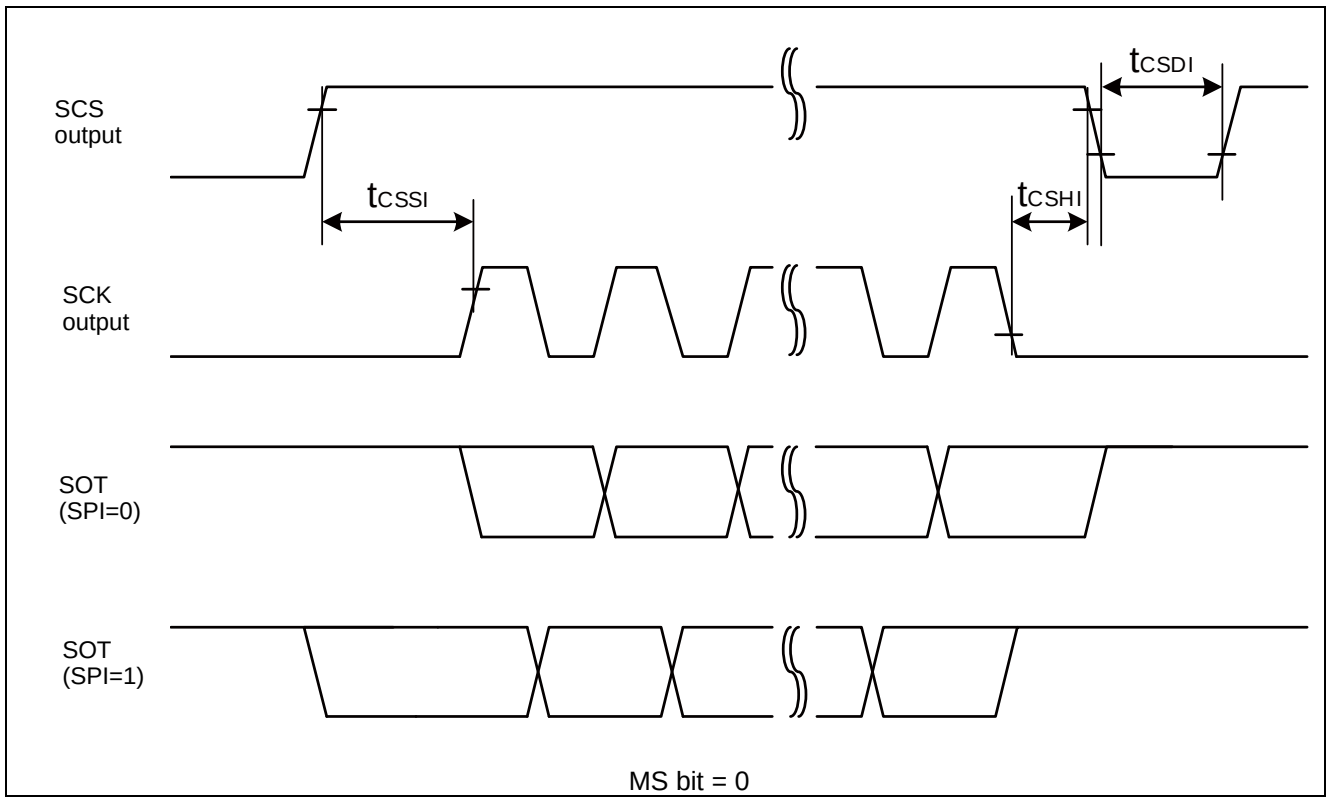
(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
Input pulse width	t_{TRGH}, t_{TRGL}	TIOAn/TIOBn (when using as TGIN)	-	$2t_{CYCP}$	-	ns	

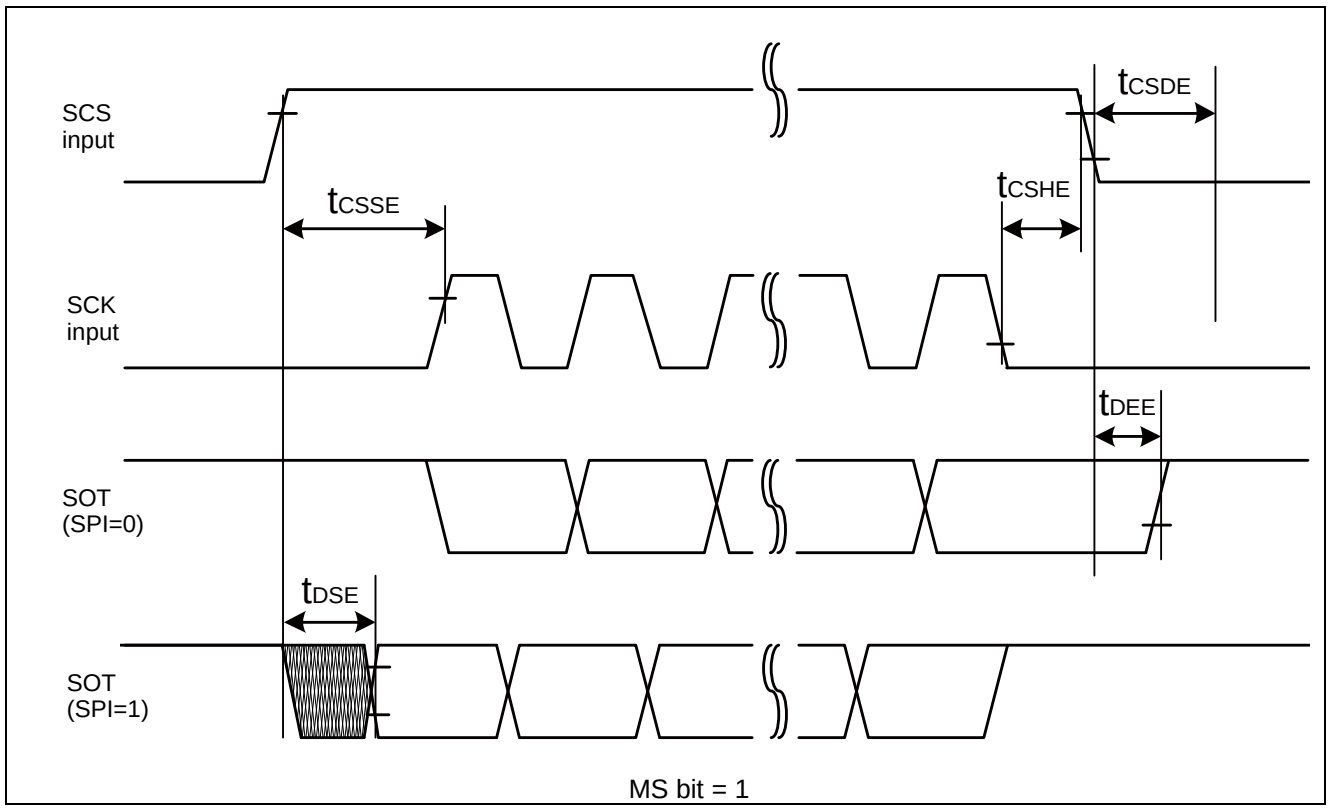


Note:

- *t_{CYCP} indicates the APB bus clock cycle time. For more information about the APB bus number to which the base timer is connected, see 8. Block Diagram in this data sheet.*



MS bit = 0



MS bit = 1

High-Speed Synchronous Serial (SPI = 0, SCINV = 1)

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

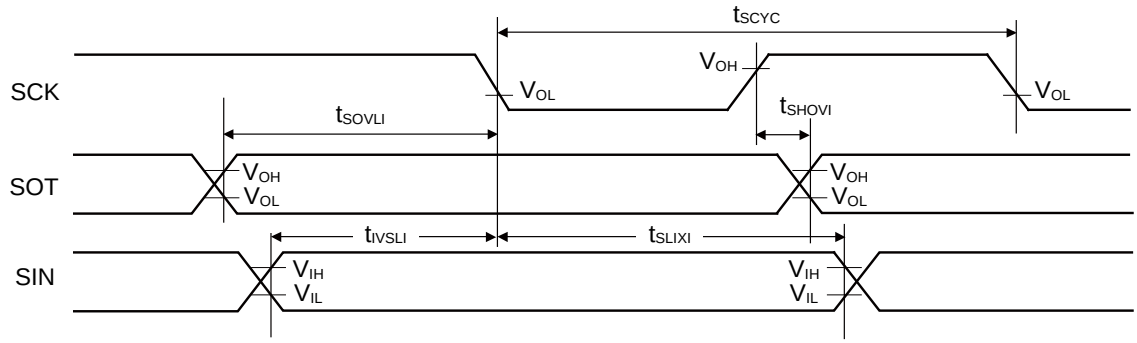
Parameter	Symbol	Pin Name	Conditions	V_{CC} < 4.5 V		V_{CC} ≥ 4.5 V		Unit
				Min	Max	Min	Max	
Serial clock cycle time	t_{SCYC}	SCKx	Internal shift clock operation	$4t_{CYCP}$	-	$4t_{CYCP}$	-	ns
SCK↑→SOT delay time	t_{SHOVI}	SCKx, SOTx		- 10	+ 10	- 10	+ 10	ns
SIN→SCK↓ setup time	t_{IVSLI}	SCKx, SINx		14 12.5*	-	12.5	-	ns
SCK↓→SIN hold time	t_{SLIXI}	SCKx, SINx		5	-	5	-	ns
Serial clock L pulse width	t_{SLSH}	SCKx	External shift clock operation	$2t_{CYCP}$ - 5	-	$2t_{CYCP}$ - 5	-	ns
Serial clock H pulse width	t_{SHSL}	SCKx		t_{CYCP} + 10	-	t_{CYCP} + 10	-	ns
SCK↑→SOT delay time	t_{SHOVE}	SCKx, SOTx		-	15	-	15	ns
SIN→SCK↓ setup time	t_{IVSLE}	SCKx, SINx		5	-	5	-	ns
SCK↓→SIN hold time	t_{SLIXE}	SCKx, SINx		5	-	5	-	ns
SCK fall time	t_F	SCKx		-	5	-	5	ns
SCK rise time	t_R	SCKx		-	5	-	5	ns

Notes:

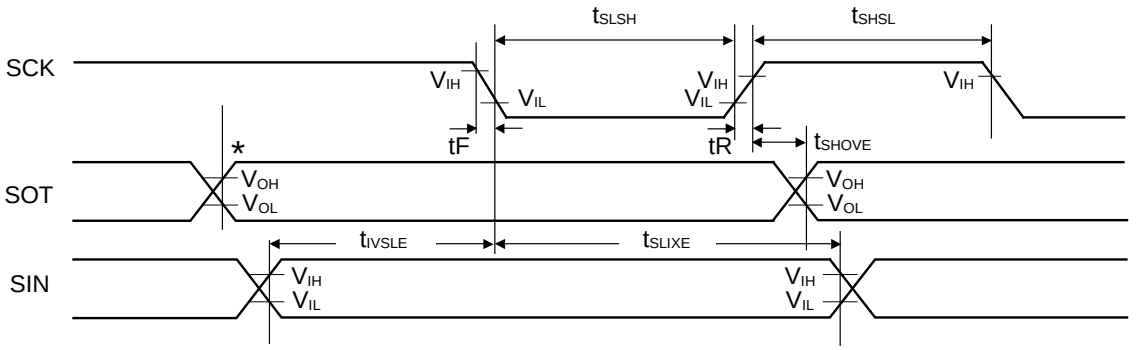
- *The above characteristics apply to CLK synchronous mode.*
- *t_{CYCP} indicates the APB bus clock cycle time. For more information about the APB bus number to which the multi-function serial is connected, see 8. Block Diagram in this data sheet.*
- *These characteristics only guarantee the following pins:*

  No chip select: SIN4_0, SOT4_0, SCK4_0

  Chip select: SIN6_0, SOT6_0, SCK6_0, SCS60_0, SCS61_0, SCS62_0, SCS63_0
- *When the external load capacitance C_L = 30 pF. (For *, when C_L = 10 pF)*



MS bit = 0



MS bit = 1

*: Changes when writing to TDR register

When Using High-Speed Synchronous Serial Chip Select (SCINV = 0, CSLVL = 1)

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Conditions	V_{CC} < 4.5 V		V_{CC} ≥ 4.5 V		Unit
			Min	Max	Min	Max	
SCS↓→SCK↓ setup time	t_{CSSI}	Internal shift clock operation	(*1)-20	(*1)+0	(*1)-20	(*1)+0	ns
SCK↑→SCS↑ hold time	t_{CSHI}		(*2)+0	(*2)+20	(*2)+0	(*2)+20	ns
SCS deselect time	t_{CSDI}		(*3)-20 +5t_{CYCP}	(*3)+20 +5t_{CYCP}	(*3)-20 +5t_{CYCP}	(*3)+20 +5t_{CYCP}	ns
SCS↓→SCK↓ setup time	t_{CSSE}	External shift clock operation	3t_{CYCP}+15	-	3t_{CYCP}+15	-	ns
SCK↑→SCS↑ hold time	t_{CSHE}		0	-	0	-	ns
SCS deselect time	t_{CSDE}		3t_{CYCP}+15	-	3t_{CYCP}+15	-	ns
SCS↓→SOT delay time	t_{DSE}		-	25	-	25	ns
SCS↑→SOT delay time	t_{DEE}		0	-	0	-	ns

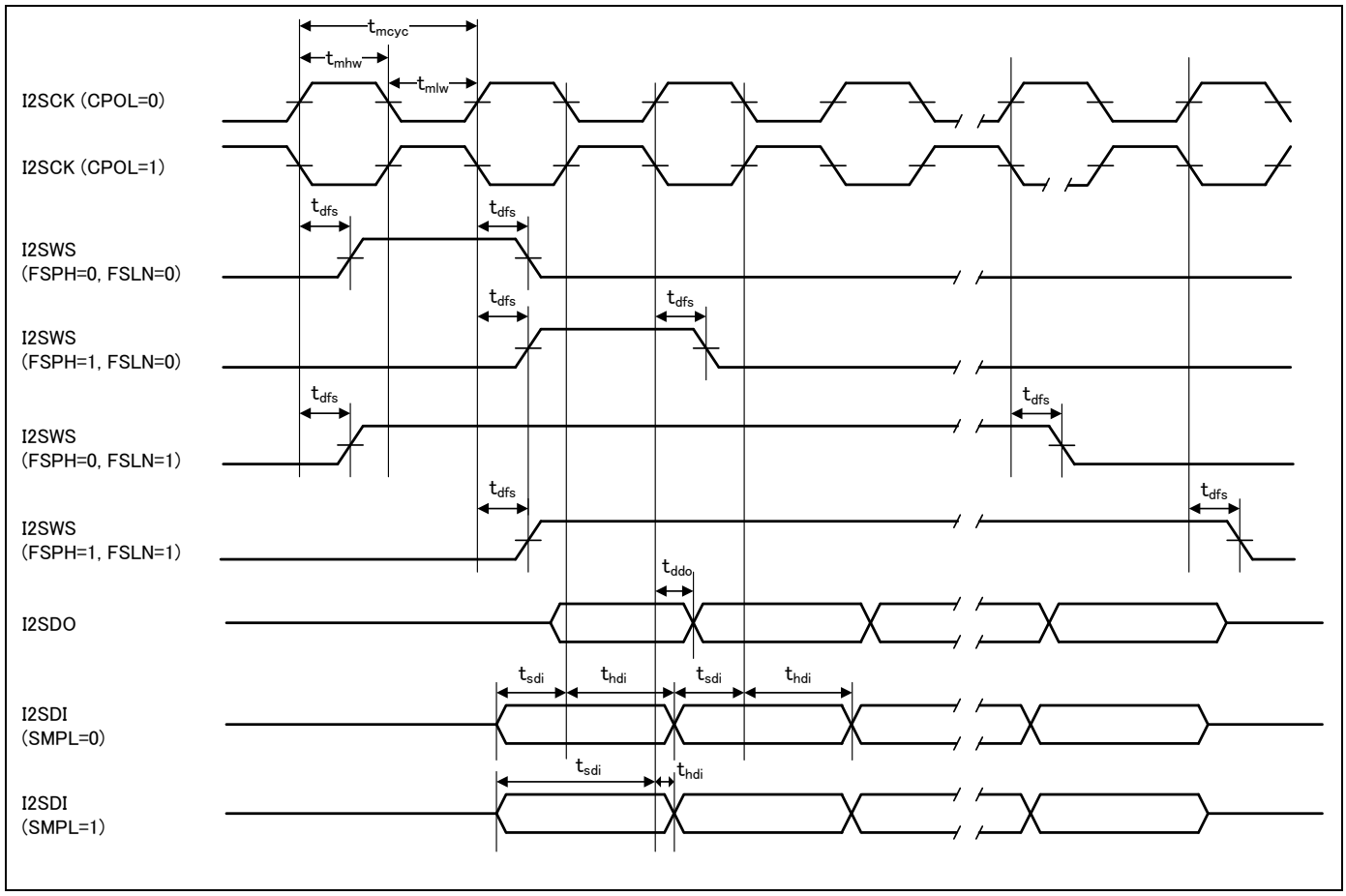
(*1): CSSU bit value×serial chip select timing operating clock cycle [ns]

(*2): CSHD bit value×serial chip select timing operating clock cycle [ns]

(*3): CSDS bit value×serial chip select timing operating clock cycle [ns]

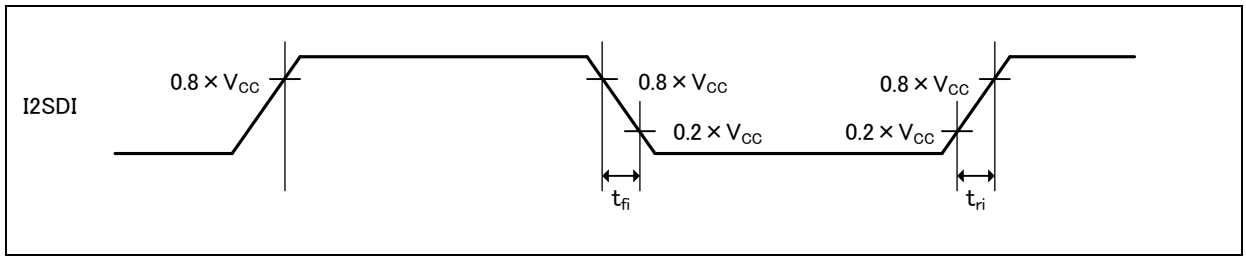
Notes:

- *t_{CYCP} indicates the APB bus clock cycle time. For more information about the APB bus number to which the multi-function serial is connected, see 8. Block Diagram in this data sheet.*
- *For more information about CSSU, CSHD, CSDS, and the serial chip select timing operating clock, see FM4 Family Peripheral Manual Main Part (002-04856).*
- *When the external load capacitance C_L = 30 pF.*



Note:

- *See Chapter7-2: I²S (Inter-IC Sound bus) Interface in FM4 Family Peripheral Manual Communication Macro Part (002-04862) for the details of CPOL, FSPH, FSLIN, and SMPL.*



Slave Mode Timing

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

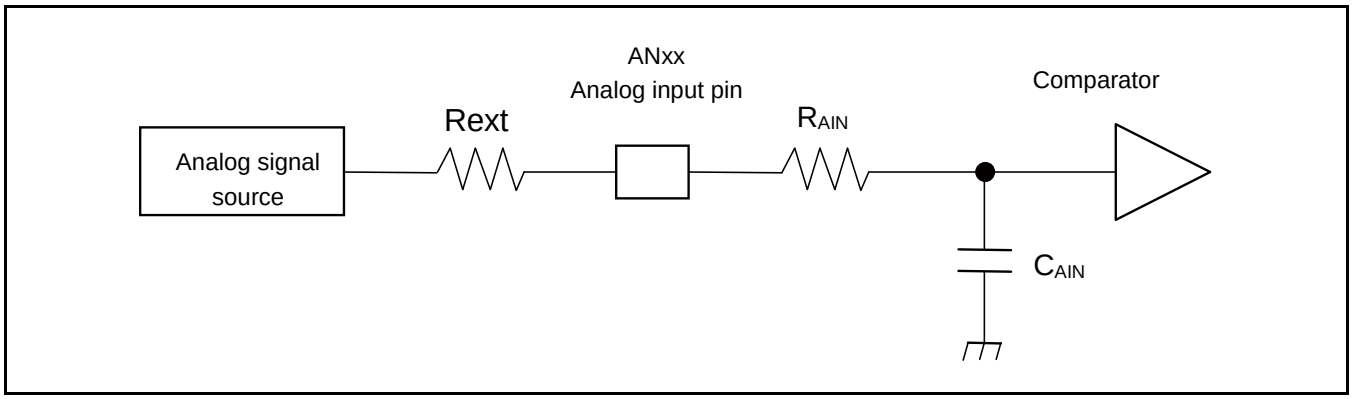
Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
Input frequency	f_{SCYC}	I2SCK	-	-	12.288	MHz	
Input clock pulse width	t_{SHW}	I2SCK	-	45	55	%	
	t_{SLW}			45	55	%	
I2SWS→I2SCK Setup time	t_{SFI}	I2SCK, I2SWS	-	8	-	ns	
I2SWS→I2SCK Hole time	t_{HFI}	I2SCK, I2SWS	-	0	-	ns	
I2SCK ↑ →I2SDO Delay time*1	t_{DDO}	I2SCK, I2SDO	-	0	32	ns	
I2SCK ↑ →I2SDO Delay time*2	t_{DFB1}		-	0	32	ns	
I2SDI→I2SCK ↓ Setup time	t_{SDI}	I2SCK, I2SDI	-	8	-	ns	
I2SDI→I2SCK ↓ Hole time	t_{HDI}		-	0	-	ns	
Input signal rise time	t_{FI}	I2SCK, I2SWS, I2SDI	-	-	5	ns	
Input signal fall time	t_{FI}		-	-	5	ns	

*1: Except for the first bit of transmission frame

*2: When FSPH bit = 1.

Notes:

- *When the external load capacitance C_L = 20 pF*
- *When I2SWS = 48 kHz, I2MCLK = 256 ×I2SWS*
  Frame synchronization signal (I2SWS) is settable to 48 kHz, 32 kHz, 16 kHz. See Chapter7-2: I^2S (Inter-IC Sound bus) Interface in FM4 Family Peripheral Manual Communication Macro Part (002-04862) for the details.



(Equation 1) $t_S \geq (R_{AIN} + R_{ext}) \times C_{AIN} \times 9$

t_S: Sampling time

R_{AIN}: Input resistance of A/D = 1.2 kΩ at 4.5V ≤ AV_{CC} ≤ 5.5V

Input resistance of A/D = 1.8 kΩ at 2.7V ≤ AV_{CC} < 4.5V

C_{AIN}: Input capacity of A/D = 12.05 pF at 2.7V ≤ AV_{CC} ≤ 5.5V

R_{ext}: Output impedance of external circuit

(Equation 2) $t_C = t_{CCK} \times 14$

t_C: Compare time

t_{CCK}: Compare clock cycle

12.7 Low-Voltage Detection Characteristics

12.7.1 Low-Voltage Detection Reset

Parameter	Symbol	Conditions	Value			Unit	Remarks
			Min	Typ	Max		
Detected voltage	VDL	-	2.46	2.55	2.64	V	When voltage drops
Released voltage	VDH	-	2.51	2.60	2.69	V	When voltage rises

12.7.2 Interrupt of Low-Voltage Detection

Parameter	Symbol	Conditions	Value			Unit	Remarks
			Min	Typ	Max		
Detected voltage	VDL	SVHI = 00111	2.80	2.90	3.00	V	When voltage drops
Released voltage	VDH		2.90	3.00	3.11	V	When voltage rises
Detected voltage	VDL	SVHI = 00100	2.99	3.10	3.21	V	When voltage drops
Released voltage	VDH		3.09	3.20	3.31	V	When voltage rises
Detected voltage	VDL	SVHI = 01100	3.18	3.30	3.42	V	When voltage drops
Released voltage	VDH		3.28	3.40	3.52	V	When voltage rises
Detected voltage	VDL	SVHI = 01111	3.67	3.80	3.93	V	When voltage drops
Released voltage	VDH		3.76	3.90	4.04	V	When voltage rises
Detected voltage	VDL	SVHI = 01110	3.76	3.90	4.04	V	When voltage drops
Released voltage	VDH		3.86	4.00	4.14	V	When voltage rises
Detected voltage	VDL	SVHI = 01001	4.05	4.20	4.35	V	When voltage drops
Released voltage	VDH		4.15	4.30	4.45	V	When voltage rises
Detected voltage	VDL	SVHI = 01000	4.15	4.30	4.45	V	When voltage drops
Released voltage	VDH		4.25	4.40	4.55	V	When voltage rises
Detected voltage	VDL	SVHI = 11000	4.25	4.40	4.55	V	When voltage drops
Released voltage	VDH		4.34	4.50	4.66	V	When voltage rises
LVD stabilization wait time	t_{LVDW}	-	-	-	$6000 \times t_{CYCP}$*	µs	

*: t_{CYCP} indicates the APB2 bus clock cycle time.